05E 22829

BIPOLAR ANALOG INTEGRATED CIRCUIT μ PC1270H

T-74-05-01

30-50 W POWER AMPLIFIER DRIVER

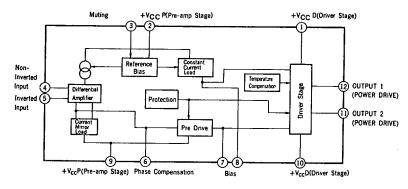
DESCRIPTION

μPC1270H is designed for use with a Hi-Fi power amplifier driver. It is composed of a differential amplifier, a predriver, a driver and protection circuit. It is in a 12 pin small power SIP. (Single In Line)

FEATURES

- · Excellent Low Distortion. 0.002 % TYP. (V_{CC} = ± 36 V, f = 1 kHz, A_v = 30 dB, P_O= 30 W, R_L = 8 Ohms) 0.006 % TYP. ($V_{CC} = \pm 36 \text{ V}$, f = 20 kHz, $A_v = 30 \text{ dB}$, $P_O = 30 \text{ W}$, $R_L = 8 \text{ Ohms}$)
- 900 kHz TYP. (-3 dB)
- Wide Power Band Width. 90 kHz TYP. (PO = 25 W, T.H.D. = 0.1 %)
- Excellent Low POP ON/OFF Noise.

BLOCK DIAGRAM



NOTE: The protection circuit is for this IC and cannot protect external Power Transistors. Thus, design a PO Tr protection circuit besides.

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ABSOLUTE MAXMUM RATINGS (Ta = 25 °C)

±50 Supply Voltage (Quiscent) V_{CC1} ±45 Supply Voltage (Operational) V_{CC2} 200 Quiscent Circuit Current mΑ I_{CC} (peak) Allowable Package Dissipation 4.1 W P_D °c -20 to +75 Operational Temperature T_{opt} \mathbf{T}_{stg} °c -40 to +150 Storage Temperature

RECOMMENDED OPERATING CONDITION

Supply Voltage (Operational)

V_{CC} = ±18 to ±36 V at MAX. Power Output

Input Bias Resistance

 R_{IN} = 1 to 50 to 100 kohms

Power Transistor heE

hFE = 50 at MAX. Power Output

Closed Loop Voltage Gain

 $A_v = 26 \text{ to } 30 \text{ dB}$

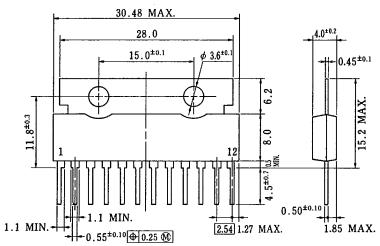
ELECTRICAL CHARACTERISTICS (V_{CC} = ± 36 V, A_{ν} = 30 dB, Use Standard Test Circuit, T_{a} = 25 °C)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITION
Output Offset Voltage	VOFF		±5	±100	m۷	SEE TEST CIRCUIT 1
Quiscent Circuit Current	lcc		20	40	mA	V _{IN} = 0
Maximum Output Voltage	Vом	20	23		٧	T.H.D. = 0.05 % f = 20 to 20 kHz
Open Loop Voltage Gain	Avo	80	95		dB	V _O = 1.5 V, f = 1 kHz
Output Noise Voltage	V _{NO}		0.07	0.14	m۷	R _G = 10 kohms
Power Band Width	P.B.W.		900		kHz	V _o = 1.5 V, -3dB
Supply Voltage Rejection Ratio	S.V.R.	55	70		dB	RG = 2 kohms, f = 100 Hz
Output Offset Voltage (Mute)	VOFF (Mute)			±50	mV	VCC=±50 V,TEST CIRCUIT 7

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12 PIN SIP (Unit : mm)

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P12HP-254B1

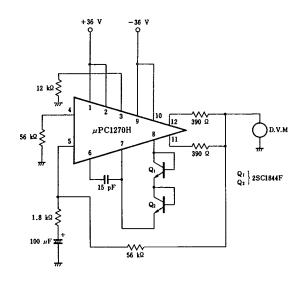
PIN CONNECTION DIAGRAM

PIN NO.	PIN CONNECTION		
1	+V _{CCD} (for Driver)		
2	+V _{CCP} (for Preamp)		
3	MUTING		
4	INPUT		
5	NFB		
6	PHASE COMP		
7	BIAS		
8	BIAS		
9	-V _{CCP} (for Preamp)		
10	-V _{CCD} (for Driver)		
11	LOWER OUTPUT		
12	UPPER OUTPUT		

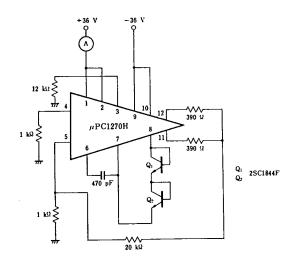
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TEST CIRCUIT 1 (VOFF)

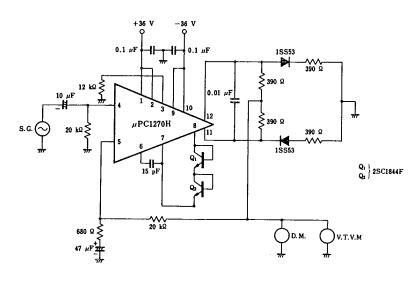
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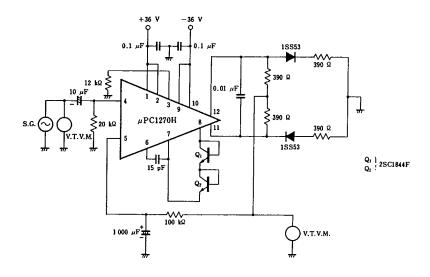
TEST CIRCUIT 2 (ICC)



TEST CIRCUIT 3 (VOM)



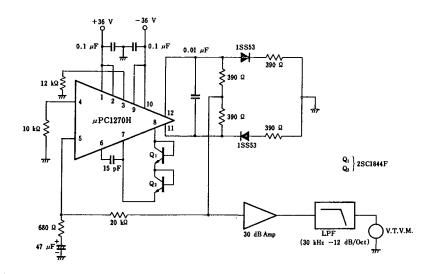
TEST CIRCUIT 4 (Avo)



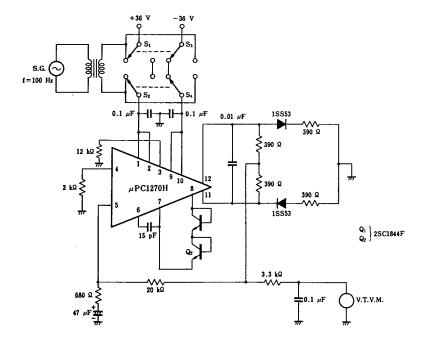


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TEST CIRCUIT 5 (VNO)



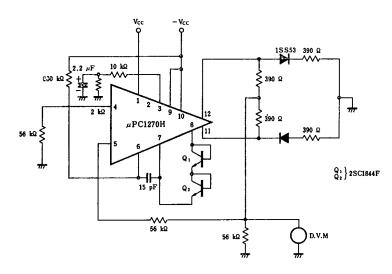
TEST CIRCUIT 6 (S.V.R.)



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TEST CIRCUIT 7 (VOFF(MUTE))

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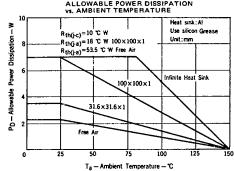


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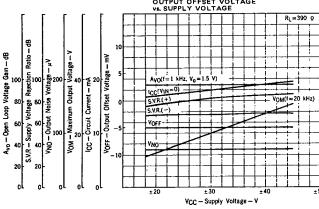
TYPICAI CHARACTERISTICS (Ta = 25°C)

ALLOWABLE POWER DISSIPATION VS. AMBIENT TEMPERATURE

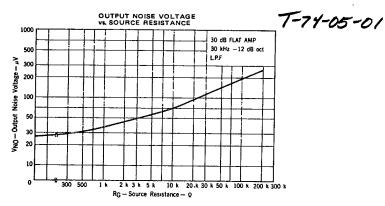


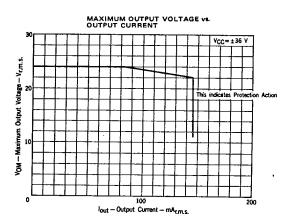
V_{CC}=36 V V_{EE}=-36 V No Phase Comp. è. Avo - Voltage A_{VO} (⑤—① Pin:15 pF, ①—② Pin:0.033 μF) f - Frequency - Hz

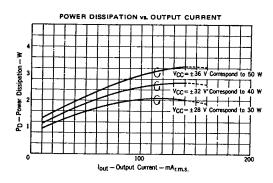
OPEN LOOP VOLTAGE GAIN
SUPPLY VOLTAGE REJECTION RATIO
OUTPUT NOISE VOLTAGE
CIRCUIT CURRENT
OUTPUT OFFSET VOLTAGE
vs. SUPPLY VOLTAGE



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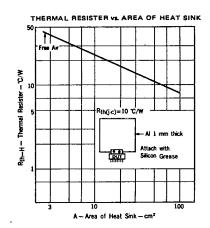




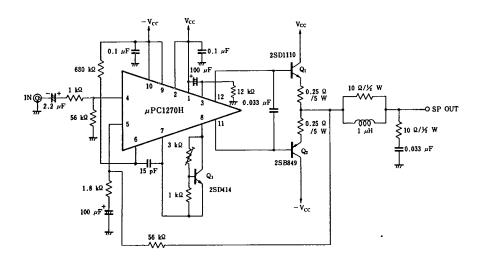


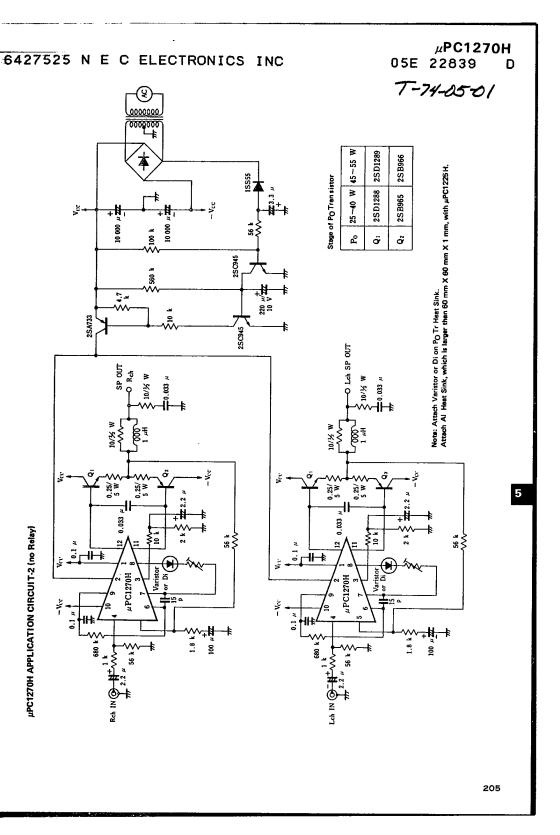


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APPLICATION CIRCUIT-1



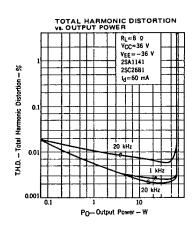


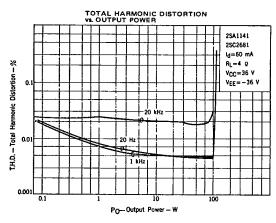
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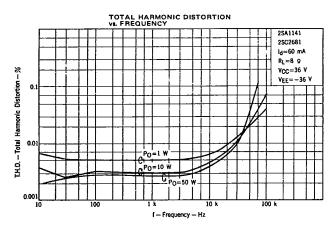
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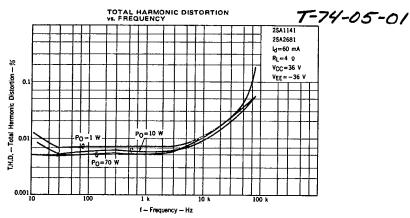
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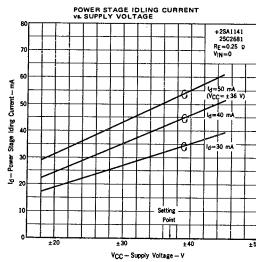






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